

Localization in an Inhomogeneous Interacting Quantum Wire

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Collaborations and Acknowledgments

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- Experiments: Hadar Steinberg, Ophir Auslaender, Amir Yacoby
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Papers:

- [cond-mat/0501684](#) (PRB 72, 045315)
- [cond-mat/0506812](#) (PRB 73, 113307)
- [arXiv:0707.2992](#) (PRB 77, 085314)

Luttinger Liquid and Momentum Resolved Tunneling between Quantum Wires

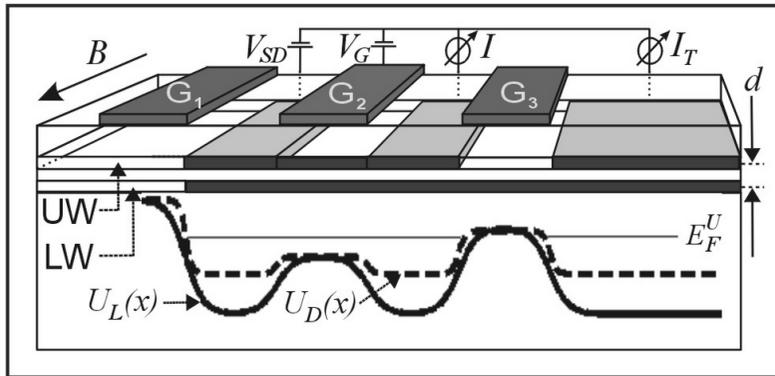
Luttinger liquid model of 1D interacting quantum system

- The Luttinger liquid is a **stable fixed point** of 1D quantum systems with gapless excitations
- The Luttinger liquid systems of 1D interacting Fermions often have **separate** spin and charge excitations propagating at different speeds
- The Luttinger liquid systems exhibit **universal** low-energy behaviors determined by only four phenomenological parameters: the velocities $v_{\rho,\sigma}$ and “interaction strength” $K_{\rho,\sigma}$ for spin and charge excitations. For a SU(2) invariant system $K_{\sigma} = 1$.

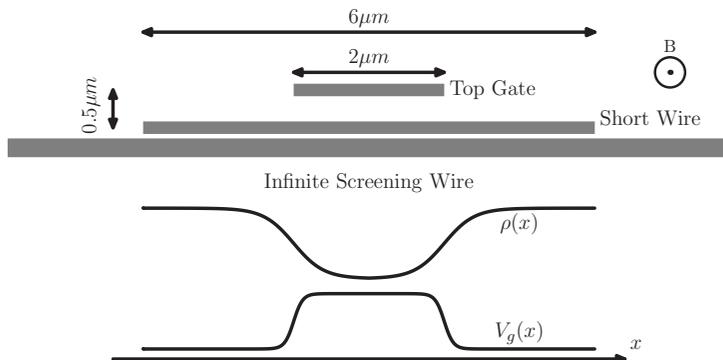
Momentum resolved tunneling as a spectroscopic tool for 1D electron system

- High mobility quantum wire formed at the edge of 2DEG is an excellent 1D interacting electron system
- Tunable tunneling conductance between the wires provide an new window into properties of the quantum wires

Schematic Diagram of Experimental Setup



Tunneling conductance is $G = dI_T/dV_{SD}$. Experiments measure dG/dV_g to pick out physics sensitive to density.



Model geometry, charge density distribution $\rho(x)$ and gate voltage V_g

Theory of Tunneling Conductance

At zero temperature, only the tunneling between ground states contributes. The tunneling conductance $G \propto |M(k_+)|^2 + |M(k_-)|^2$, where

$$k_{\pm} = \pm k_F^{lower} + e\mathbf{B}d/\hbar,$$

and

$$M(k) = \langle \Psi^N | c_k^\dagger | \Psi^{N-1} \rangle.$$

It is instructive to define a “quasi-wavefunction”:

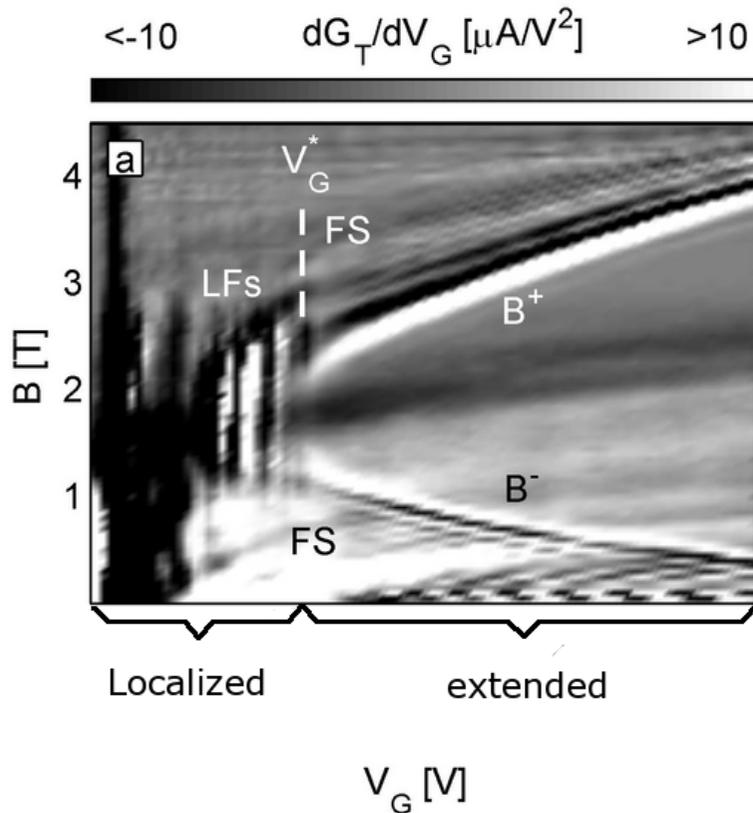
$$\Psi_{\text{eff}}^N(x) \equiv \langle \Psi_\gamma^{N-1} | \psi_\sigma(x) | \Psi_\alpha^N \rangle,$$

then

$$M(k) = \int dx e^{ikx} \Psi_{\text{eff}}^{N*}(x).$$

For non-interacting wire Ψ_{eff}^N is simply the wavefunction of last occupied electron.

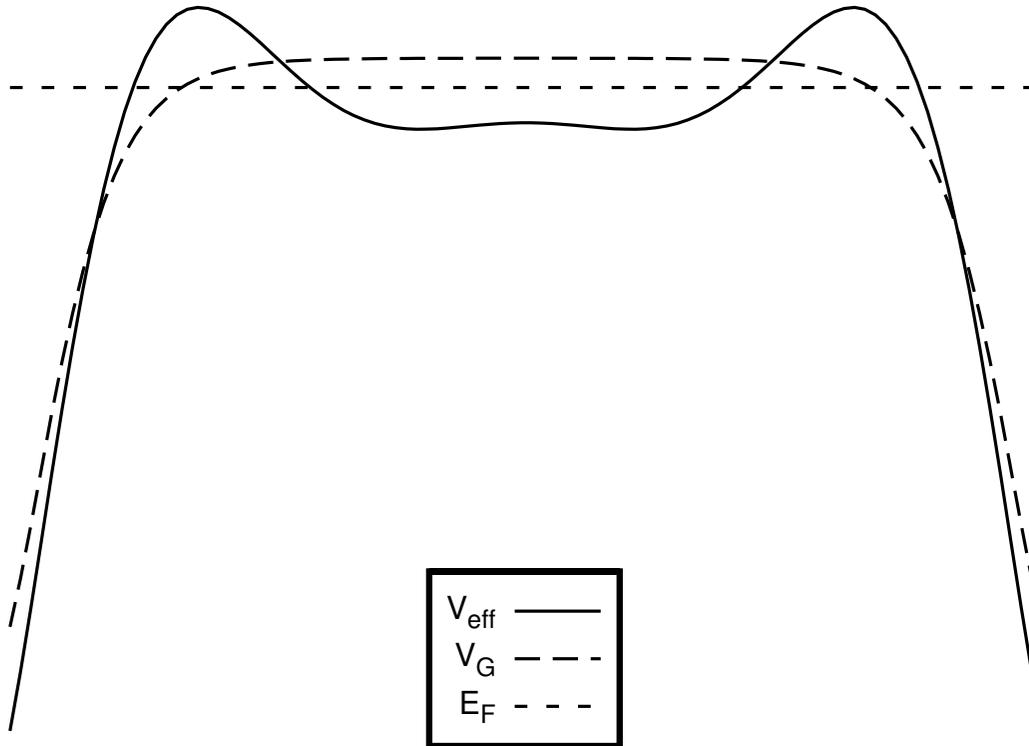
Overall Features of Experimental Data



Key Features:

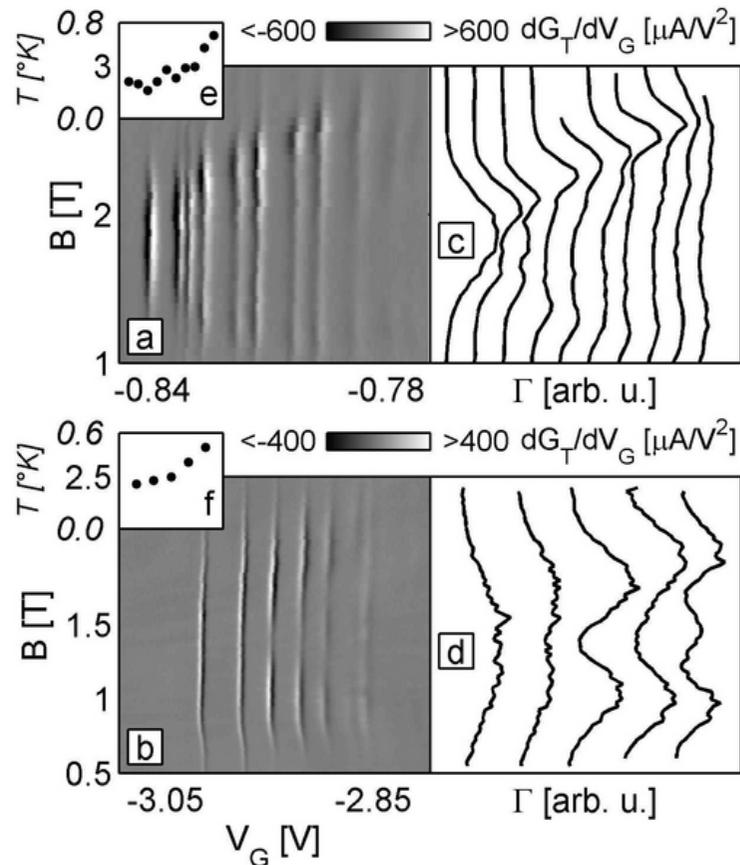
- Extended state: density n changes continuously with gate voltage V_g , momentum dependence of tunneling sharply peaked at $k = \pm k_F(n)$.
- Localized state: density n changes discretely with gate voltage V_g , momentum dependence of tunneling extended over a wide range of k .

Self-consistent Confining Potential Generated by Interaction?



hypothetical self-consistent potential in the localized phase

Part I: Momentum Dependence of Tunneling Conductance

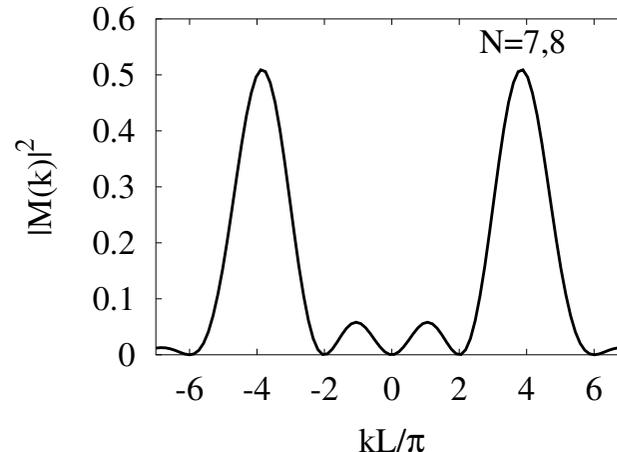
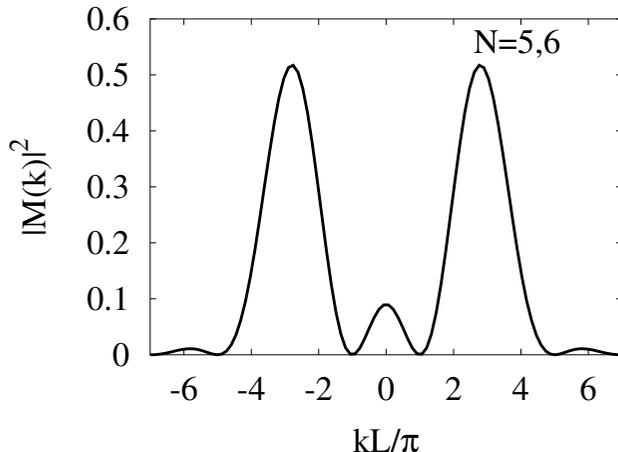
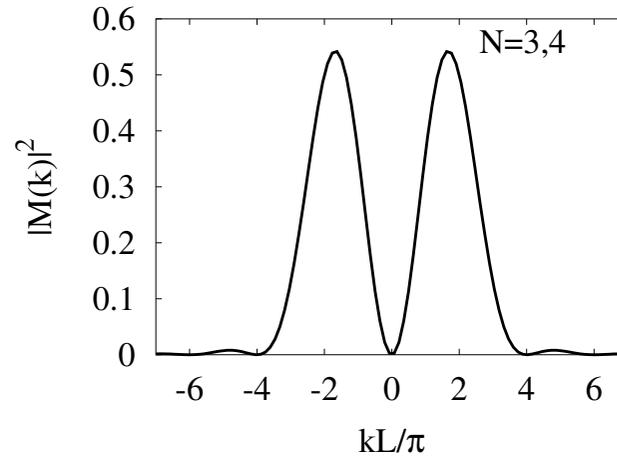
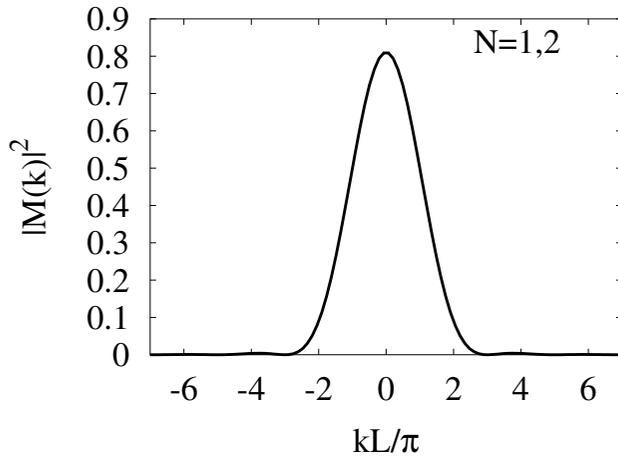


Basic features of momentum distribution:

- Broad momentum distribution, implying localized electrons
- Typically two broad peaks, the separation between which widens with increasing particle number N
- Last Coulomb blockade peak has single peak in momentum distribution

Non-interacting Electrons, $T = 0$, Box with Hard Wall

As large N , $|M(k)|^2$ becomes peaked at $k_N = N\pi/L$ with width $\delta k = 2\pi/L$.

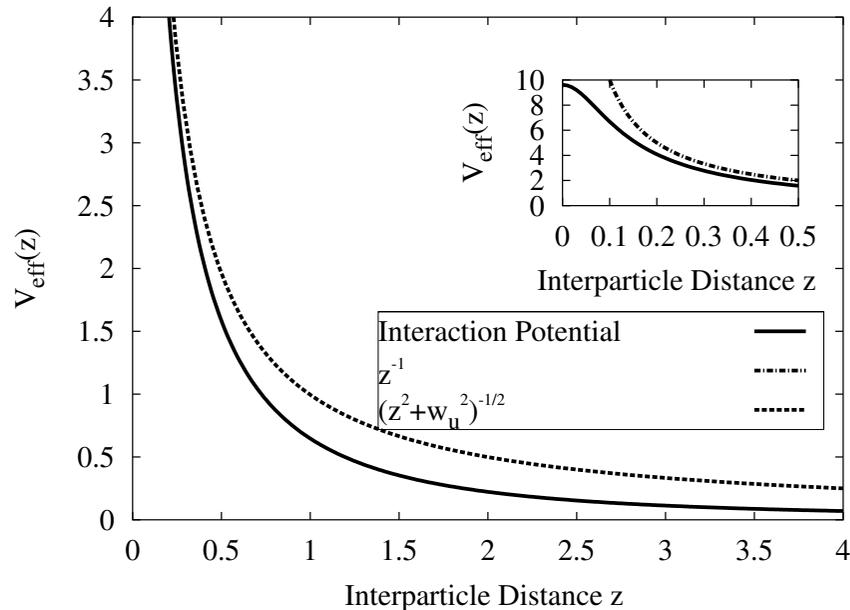


Screened Coulomb Interaction Potential

The Coulomb interaction in the short upper wire is assumed to have a **short-range** cutoff due to the finite width of the wire and **long-range** cutoff due to screening by the more conducting lower wire.

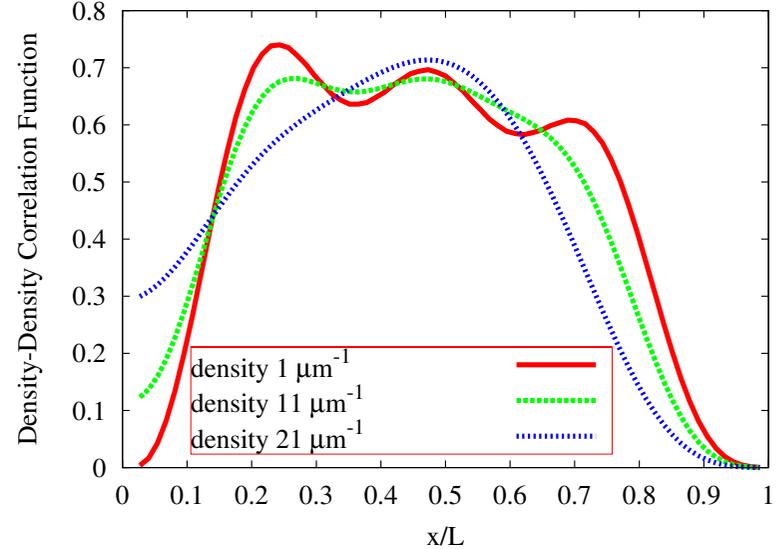
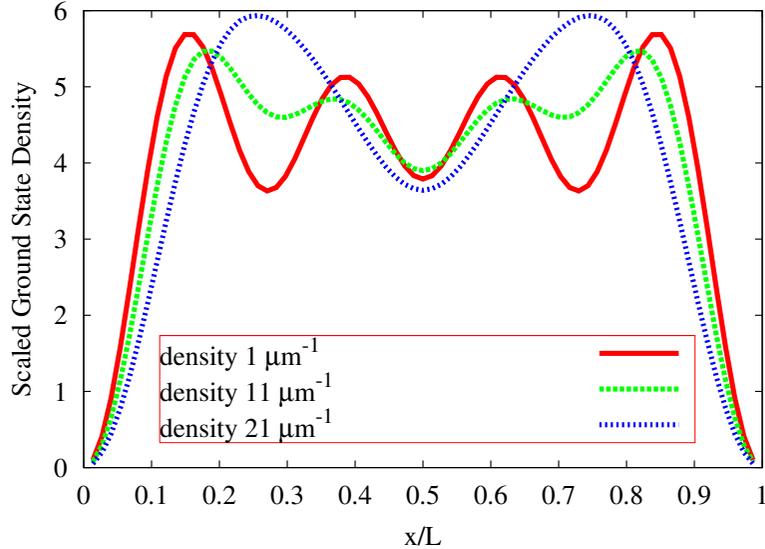
$$\tilde{V}_{\text{eff}}(q) = \tilde{V}_0(q, W_u) - \frac{\tilde{V}_0^2(q, d)}{\tilde{V}_0(q, W_l)},$$

where $\tilde{V}_0(q, W) = \int_{-\infty}^{\infty} dx \frac{e^{iqx}}{\sqrt{x^2 + W^2}} = 2K_0(Wq)$. K_0 is modified Bessel function.



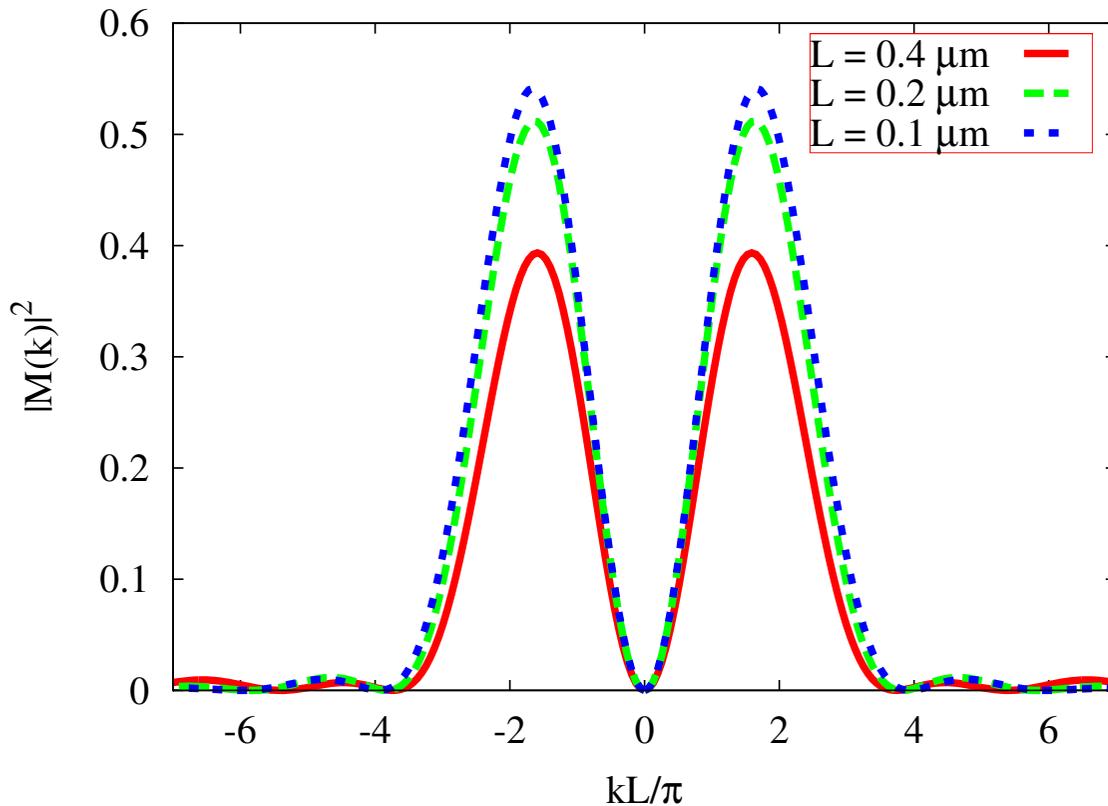
Formation of Quasi-Wigner Crystal Order with Lowering Density

Instead of the Friedel oscillation of frequency $2\mathbf{k}_F$, clear oscillations of frequency $4\mathbf{k}_F$ show up, both in density and in density-density-correlation, at low density. Here density-density correlation function is defined as $\frac{1}{1-x} \int_0^{1-x} \rho(x')\rho(x'+x)dx'$.



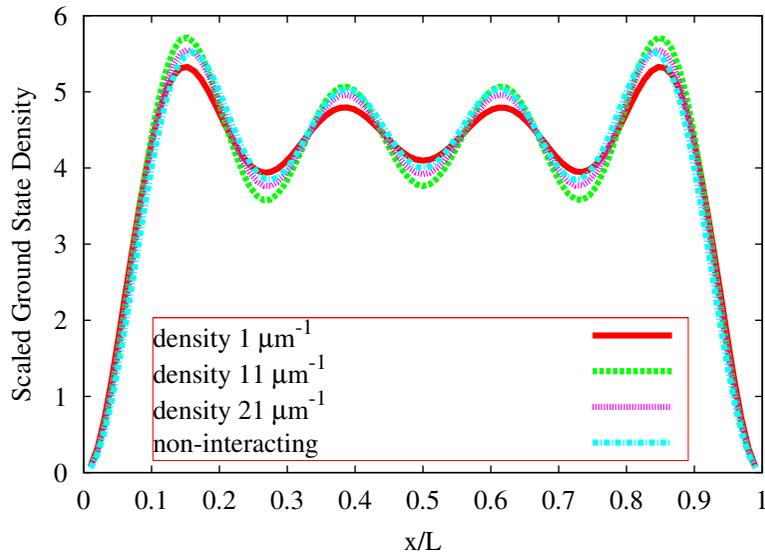
Ground State Tunneling: Exact-Diagonalization

$|M(k)|^2$ is insensitive to interactions. Following plot show $|M(k)|^2$ for tunneling from $N = 3$ to $N = 4$ state.

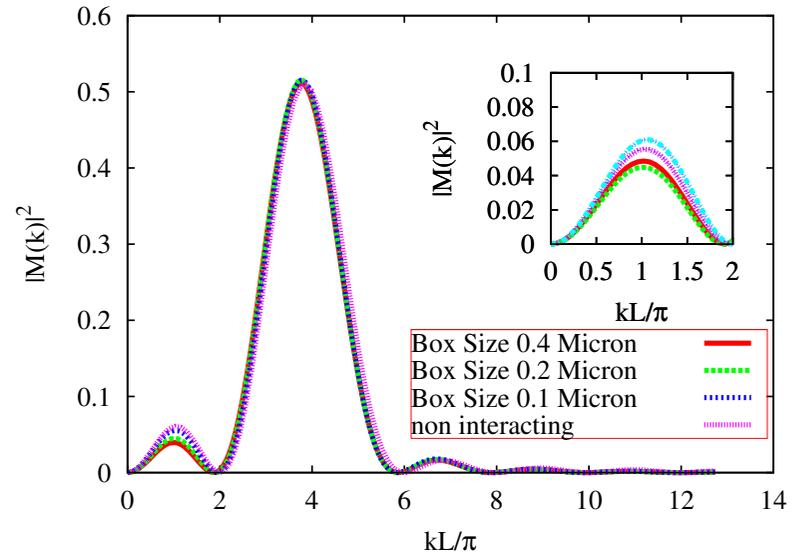


Spinless/Polarized Electrons

Under the experimental parameters, spinless electrons are essentially non-interacting for both high and low density.



(i) Density of Four Interaction Spinless Electrons



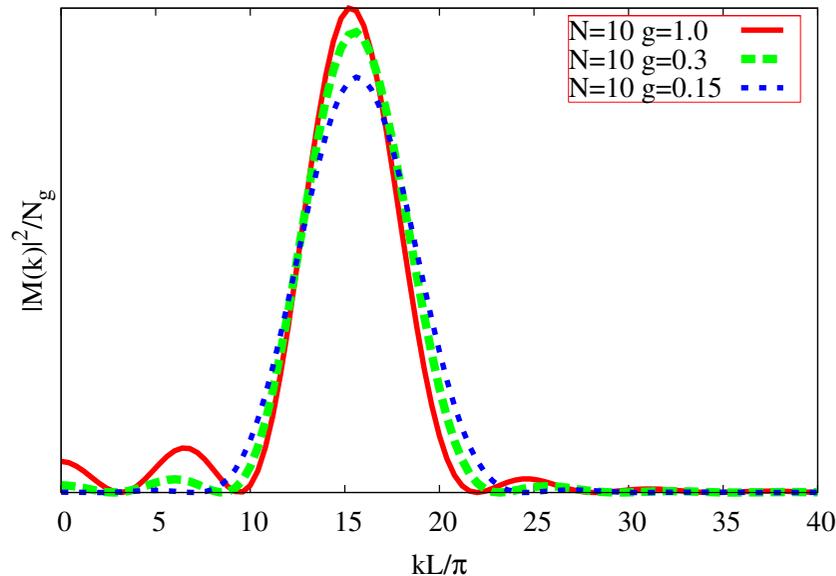
(j) Tunneling of Three to Four spinless Electron

Large- N limit: Ground State Tunneling

For large but finite N and not too close to wall, Luttinger liquid theory gives an estimate of the ground state quasi-wavefunction as defined before:

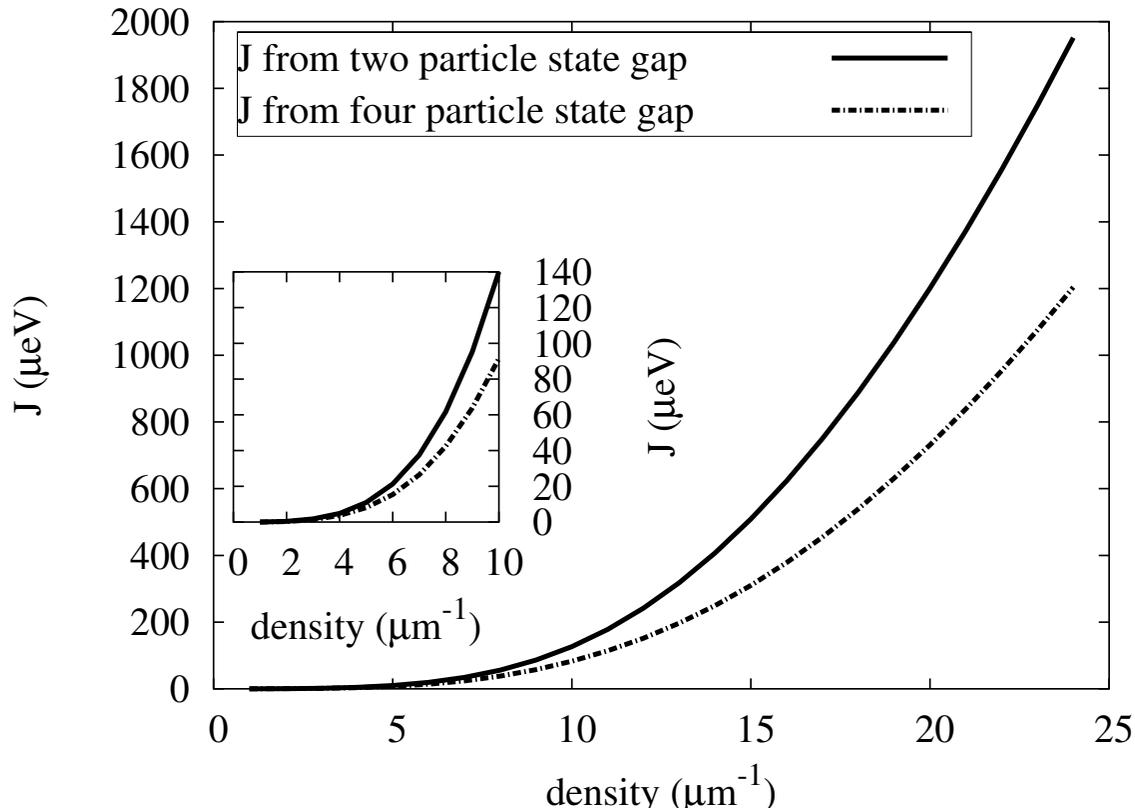
$$\Psi_{\text{eff}}^N(x) \sim \frac{1}{\sqrt{LN^\alpha}} \left[\sin\left(\frac{\pi x}{L}\right) \right]^{\frac{1}{2}(\alpha_{\text{end}} - \alpha)} \sin(k_F x),$$

where tunneling exponent for bulk and end is given by Luttinger liquid interaction parameter g as $\alpha = (g + g^{-1} - 2)/4$ and $\alpha_{\text{end}} = (g^{-1} - 1)/2$, respectively. A normalization factor N_g is used so that the integrated areas under the three curves are the same.



Estimates of Effective Heisenberg Exchange Constant J

At strong interaction, the dynamics of system can be described by Heisenberg model. The Heisenberg exchange parameter J can be extracted from gap Δ between ground state and first excited state. For $N = 2$ $J = \Delta$ and for $N = 4$ $J = 1.5178\Delta$.



Tunneling Conductance at Finite Temperature

Total Conductance $G = C(\mathcal{B}(k_+) + \mathcal{B}(k_-))$, where

$$\mathcal{B}(k) = \sum_{\alpha\gamma\sigma} |\langle \Psi_\alpha^N | c_{k\sigma}^\dagger | \Psi_\gamma^{N-1} \rangle|^2 w_{\alpha\gamma},$$

$$\begin{aligned} w_{\alpha\gamma} &= e^{-\beta[E_\gamma^{N-1} - \mu(N-1)]} f(\epsilon_{\alpha\gamma}) \\ &= e^{-\beta(E_\alpha^N - \mu N)} [1 - f(\epsilon_{\alpha\gamma})], \end{aligned}$$

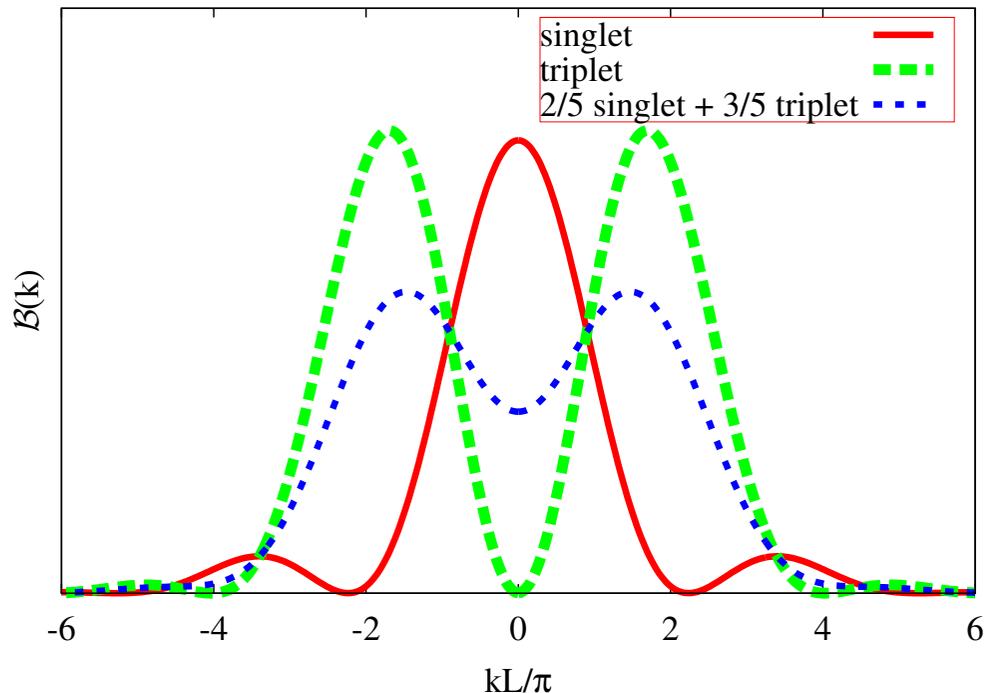
$$k_\pm = \pm k_F^l + eBd/\hbar.$$

$$\epsilon_{\alpha\gamma} = E_\alpha^N - E_\gamma^{N-1},$$

$$C = \frac{\pi e^2}{2\hbar} \lambda^2 \beta v L \frac{e^{-\beta\mu N}}{Z_N + e^{-\beta\mu} Z_{N-1}},$$

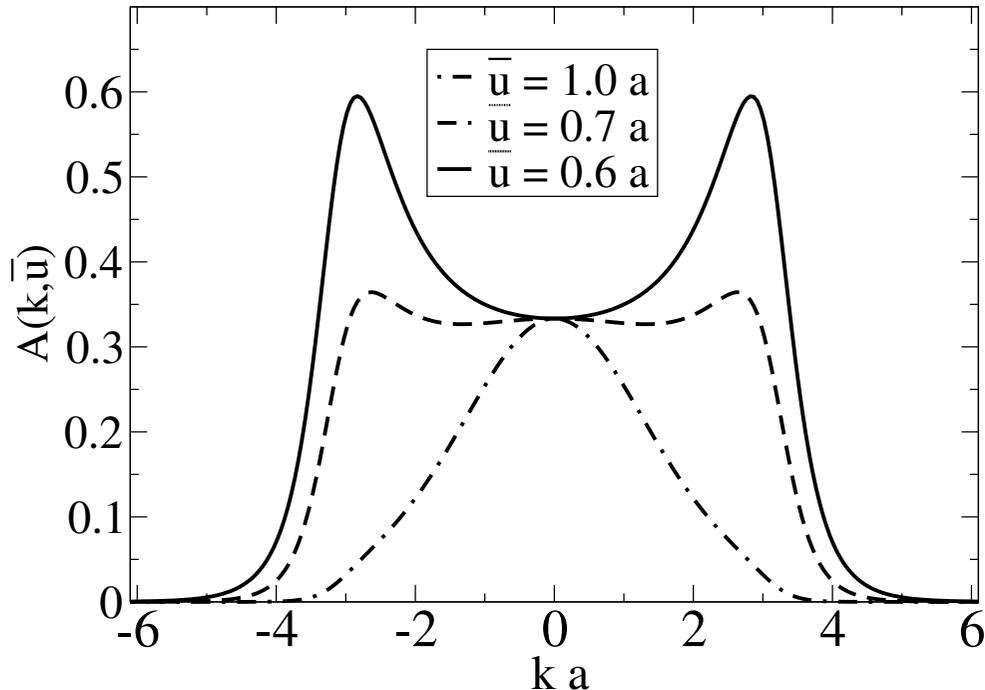
Finite Temperature and Mixing Spins: Exact Diagonalization

For strong repulsive interaction, spin excitation energy scale $\Delta = J/N$ may become very small. Three energies scales are important: spin gap Δ , Zeeman energy E_Z and thermal energy $k_B T$. Following picture shows tunneling from $N = 1$ to $N = 2$: the case of singlet ground state ($E_Z < \Delta$), triplet ground state ($E_Z > \Delta$) and high temperature mixed state ($E_Z, \Delta \ll k_B T \ll \Delta_{charge}$).



Finite Temperature and Mixing Spins: Free Spin Regime and Large N limit

If $J \ll k_B T \ll \hbar v_c k_F$, spin configurations have equal thermal weight but there's no charge excitation, we find a spectral weight as following:



Here $\bar{u} = \frac{a}{\pi} \sqrt{2g \ln(L/a)}$ is the root-mean-square fluctuation of electron position. g is the Luttinger liquid interaction parameter.

Conclusions for Part I

We investigated the momentum dependence of tunneling matrix elements from a infinite wire into short quantum containing interacting electrons.

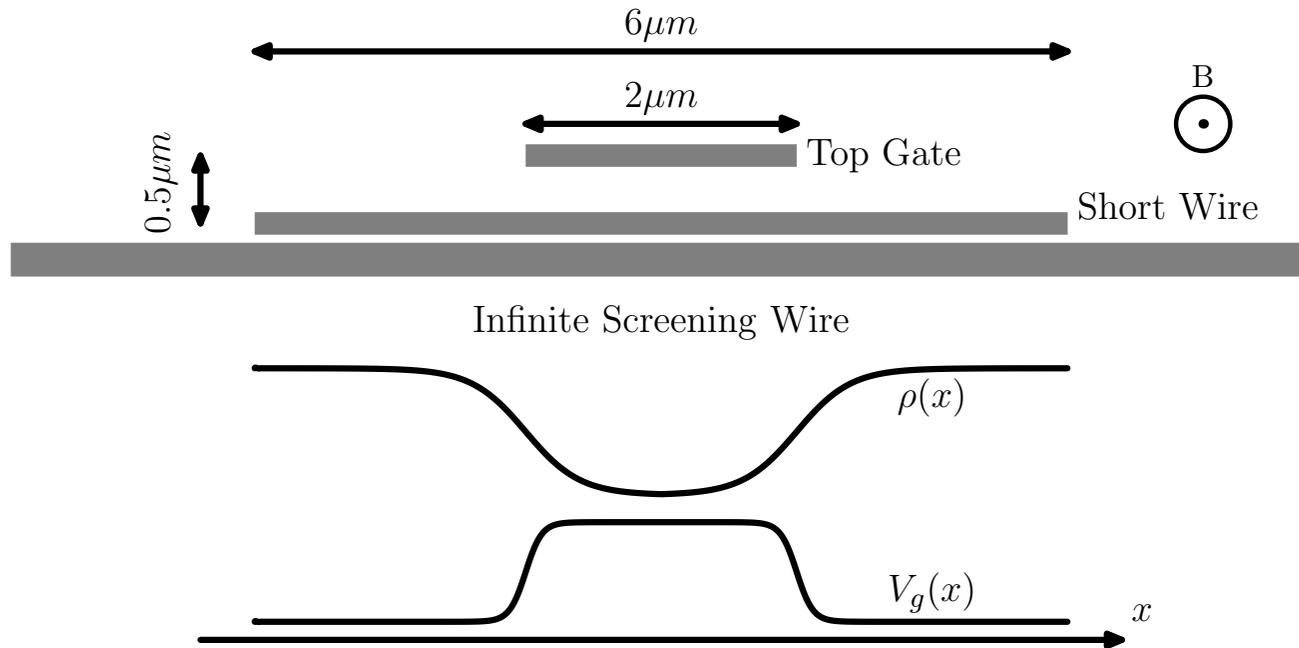
- For $N \leq 4$ exact diagonalization is carried out, ground state tunneling matrix element $|M(k)|^2$ is computed.
- Large N calculations of tunneling amplitude, both for ground state tunneling and for free spin regime, are carried out using Luttinger liquid theory.

Other Possible Factors in Accounting for Experimental Observation

- Soft instead of hard wall confinement: more spectral weight at center.
- Partial spin polarization
- Asymmetry of confinement potential

Part II: Electronic States of Low Density Region

Model geometry for the electronic density distribution $\rho(x)$ and gate potential $V_g(x)$



The Restricted Hartree-Fock Hamiltonian

Assumptions and simplifications of the Hartree-Fock model:

- Spin restricted to be either aligned or anti-aligned with magnetic field B
- Two subbands corresponding to different transverse modes in the quantum wire
- Electrons in different subbands interact only through Hartree terms

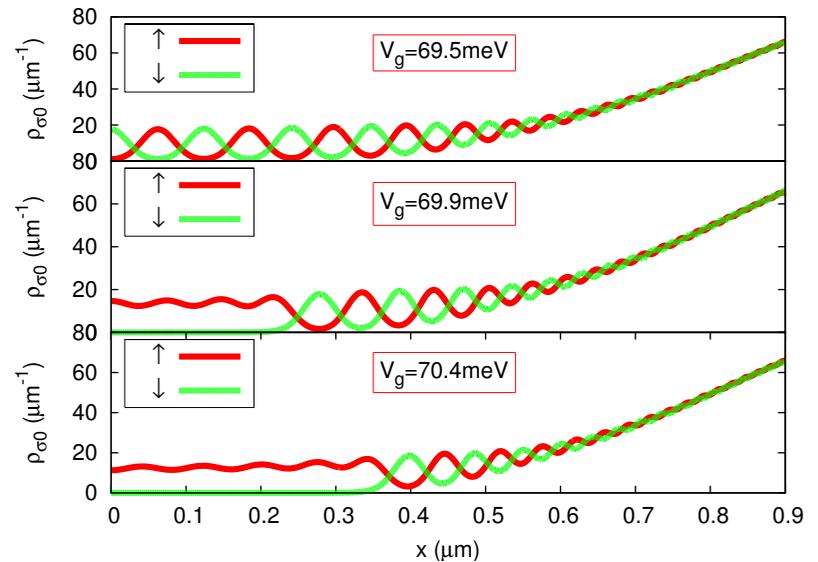
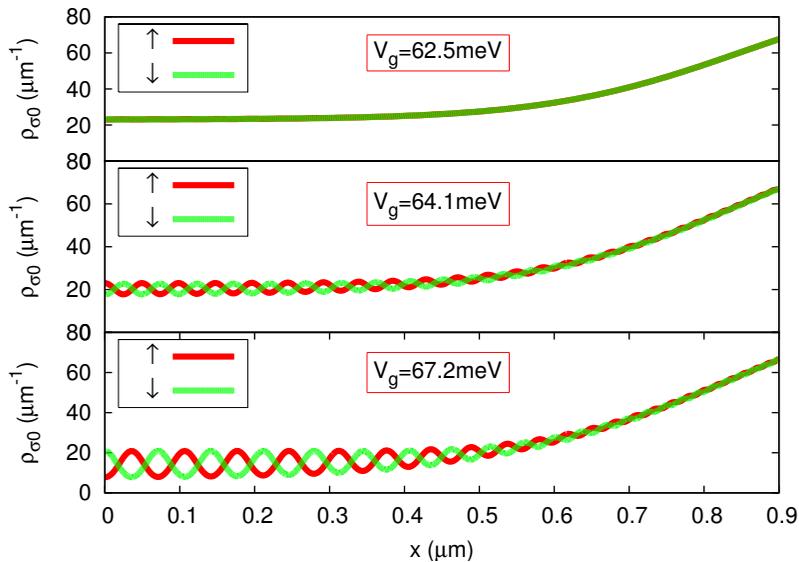
$$H\psi_{\sigma b}(x) = -\frac{\hbar^2}{2m^*} \frac{\partial^2 \psi_{\sigma b}(x)}{\partial x^2} + (V_G(x) + \Delta_b) \psi_{\sigma b}(x) + \mu_B B S_z \psi_{\sigma b}(x) \\ + V_H(x) \psi_{\sigma b}(x) - \int dx' V_F^{\sigma b}(x, x') \psi_{\sigma b}(x')$$

$$V_H(x) = \int dx' \left(\sum_{i, \sigma', b'} |\psi_{i\sigma'b'}(x')|^2 \right) V_{\text{eff}}(x - x')$$

$$V_F^{\sigma b} = \sum_i \psi_{i\sigma b}(x) \psi_{i\sigma b}^*(x') V_{\text{eff}}(x - x').$$

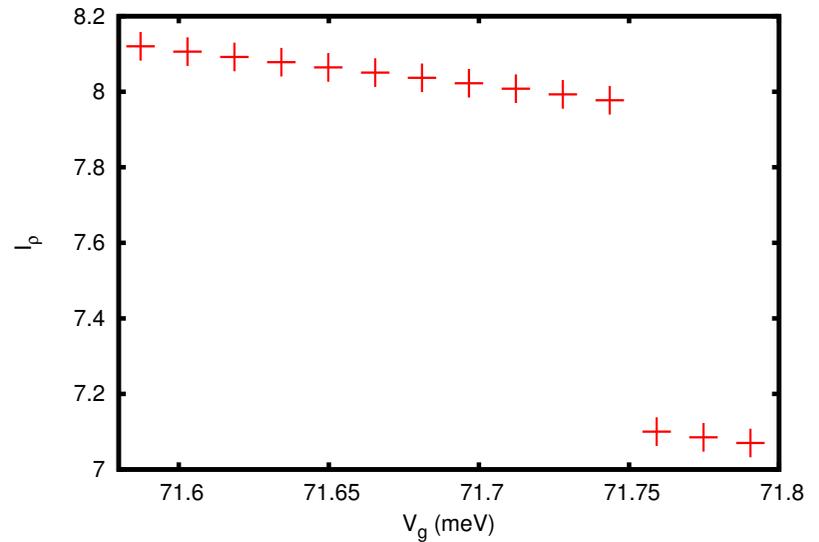
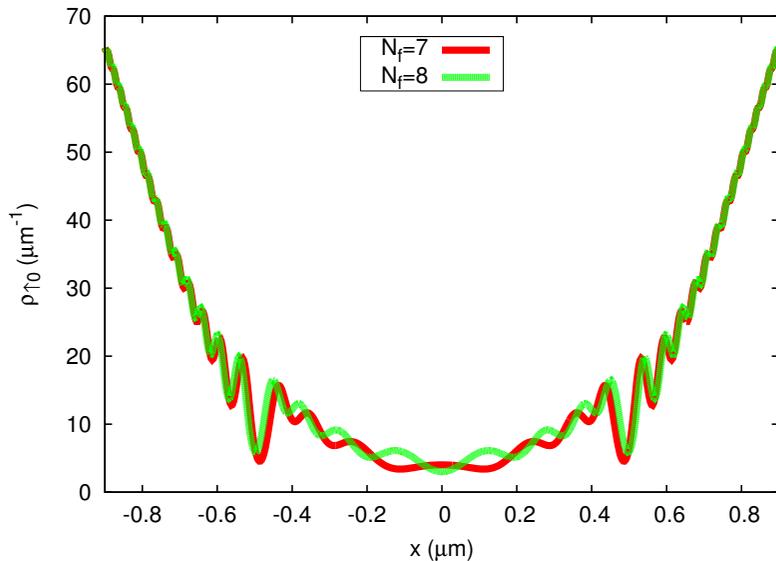
Magnetic Phases at the Low Density Region

- The emergence of an antiferromagnetic order at the low density region (left)
- The emergence of spin-aligned region at the center of the wire (right)



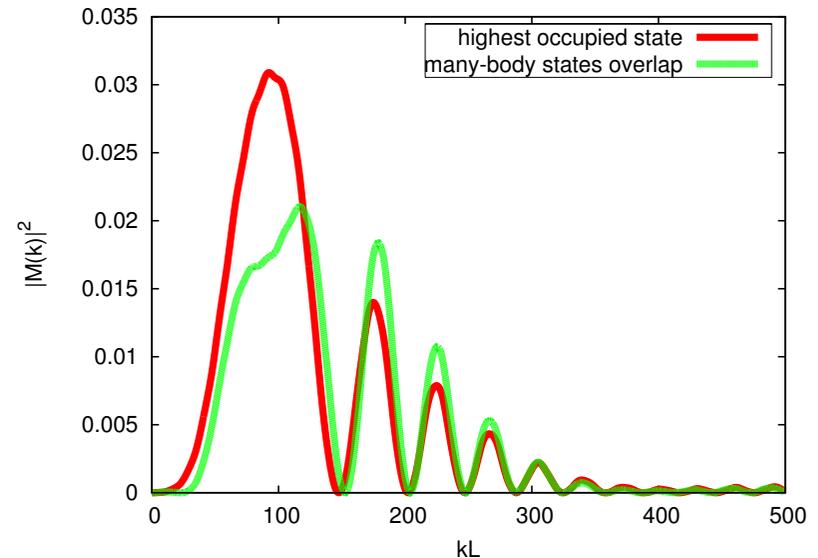
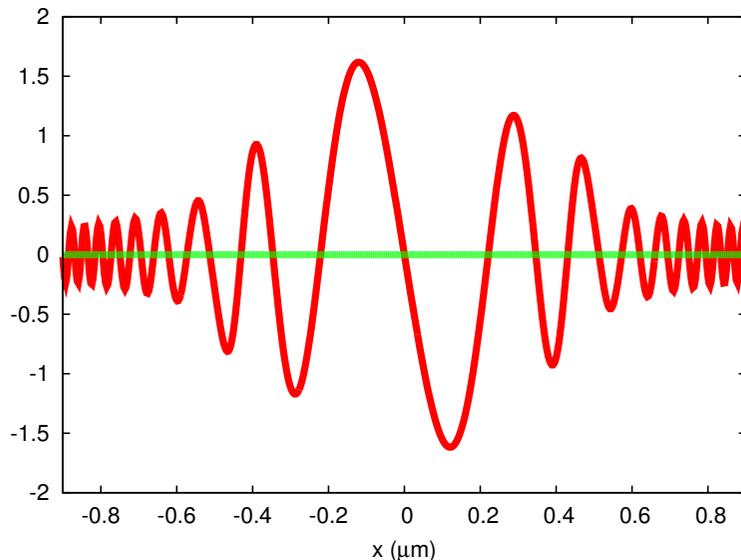
Discrete Density Changes in the Spin-aligned Phase

Abrupt density rearrangements occur due to the successive expulsion of a single electron from the spin-aligned region



Nature of Electronic States in the Spin-aligned Region

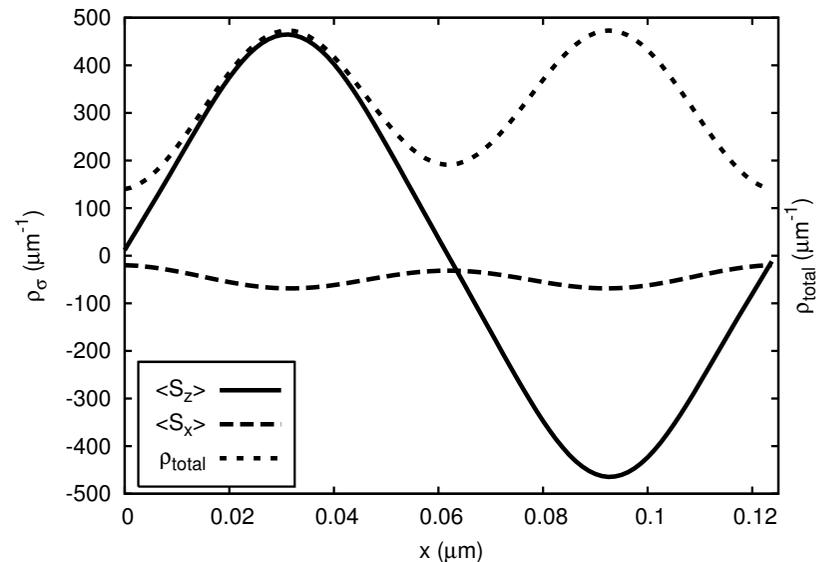
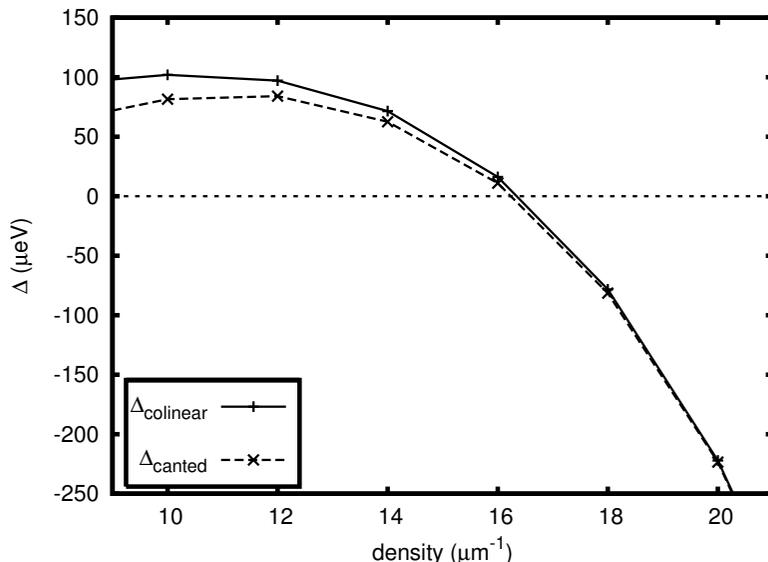
- The wavefunctions near the Fermi level have large weights near the center
- No sign of self-consistent barrier at the ends of spin-aligned region
- Little spectral weight near $k = 0$ in the momentum-dependent tunneling matrix element



Left wavefunction of $N = 7$ solution at E_f Right transition from $N = 7$ to $N = 8$ solutions

Unrestricted Hartree-Fock in a Homogeneous system: Effects of Canting in the Antiferromagnetic Phase

- The correction to the energy per unit cell due to canting is small in the range where the ground state is antiferromagnetic
- The S_x magnetization is small for canted solution at $\rho = 16\mu m^{-1}$, where the system make a transition to a ferromagnetic ground state



Conclusions for Part II

We investigated the density and spin configuration an inhomogeneous quantum wire using the restricted Hartree-Fock method. We found:

- When lowering its density, the depleted region goes from a non-magnetic state to an antiferromagnetic state, and finally to a spin-aligned state sandwiched by antiferromagnetic states
- In the spin-aligned phase, the spin-aligned region undergoes abrupt density changes by successively losing a single electron
- The wavefunctions near the Fermi surface are relatively localized near the center, but they are not Coulomb-blockade states confined by barrier potentials
- Additional mechanisms, such as impurity potentials or multiple spin state contributions, are needed to explain the observed large spectral weight near $k = 0$ in the momentum dependent tunneling
- In our model, the effects due to the canting of the spins in the unrestricted Hartree-Fock model are small